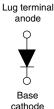


High Performance Schottky Rectifier, 240 A





HALF-PAK (D-67)

anode
Q
lacksquare
Y
Ó
Base
cathode

PRIMARY CHARACTERISTICS				
I _{F(AV)} 240 A				
V_{R}	45 V			
Package	HALF-PAK (D-67)			
Circuit configuration	Single diode			

FEATURES

- 150 °C T_{.I} operation
- · Low forward voltage drop
- High frequency operation



- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-240NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS VALUES			
I _{F(AV)}	Rectangular waveform	240	A	
V _{RRM}		45	V	
I _{FSM}	t _p = 5 μs sine	26 000	A	
V _F	240 A _{pk} , T _J = 125 °C	0.64	V	
T _J	Range	-55 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-240NQ045PbF	UNITS	
Maximum DC reverse voltage	V_{R}	45	V	
Maximum working peak reverse voltage	V _{RWM}	45	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 104 °	C, rectangular waveform	240	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	26 000	Α
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	3400	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 18 A, L = 1 mH		162	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical 48		А	



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	240 A	T _J = 25 °C	0.72	V
Maximum forward voltage drop		480 A		1.04	
See fig. 1		240 A	T _J = 125 °C	0.64	
		480 A		0.97	
Maximum reverse leakage current per leg	Maximum reverse leakage current per leg		V _R = Rated V _R	20	mA
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = nateu V _R	1120	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		14 800	pF
Typical series inductance	L _S	From top of terminal hole to mounting plane		5.0	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/		V/µs	

Note

 $^{(1)}$ Pulse width $< 500 \ \mu s$

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-55 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	0.19	20044	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.05	°C/W	
Approximate weight				30	g	
Approximate weight				1.06	oz.	
minimum				3 (26.5)		
Mounting torque	maximum		Non-lubricated threads	4 (35.4)	N · m (lbf · in)	
Tayminal tayaya	minimum			3.4 (30)		
Terminal torque — maxir				5 (44.2)		
Case style				HALF-PAK	(module	

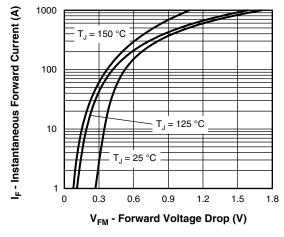


Fig. 1 - Maximum Forward Voltage Drop Characteristics

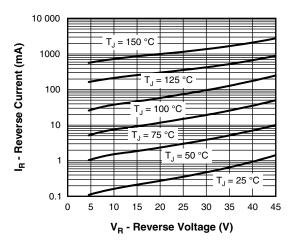


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

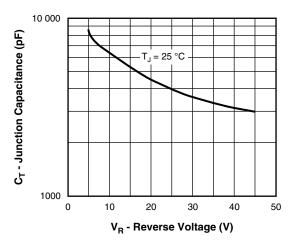


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

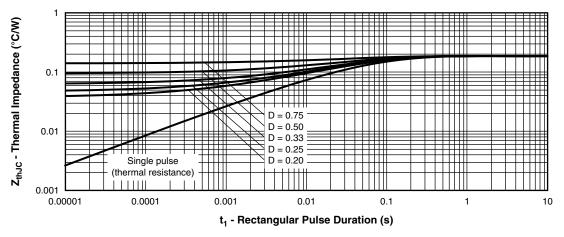


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

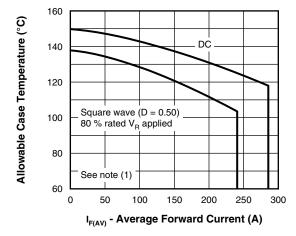


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

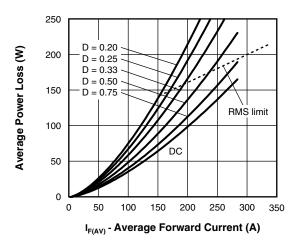


Fig. 6 - Forward Power Loss Characteristics

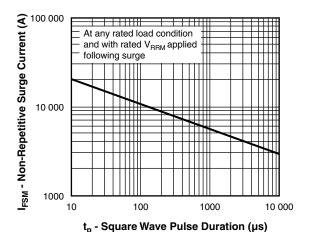


Fig. 7 - Maximum Non-Repetitive Surge Current

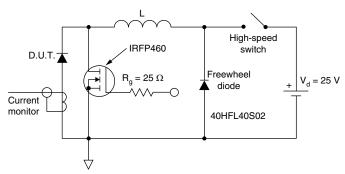


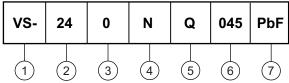
Fig. 8 - Unclamped Inductive Test Circuit

Note

Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Average current rating (x 10)
- Product silicon identification
- 4 N = not isolated
- 5 Q = Schottky rectifier diode
- 6 Voltage rating (045 = 45 V)
- 7 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95020			



D-67 HALF-PAK

DIMENSIONS in millimeters (inches)









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